

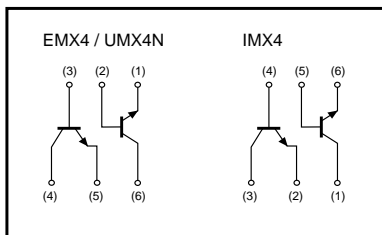
High transition frequency (dual transistors)

EMX4 / UMX4N / IMX4

●Features

- 1) Two 2SC3837K chips in a EMT or UMT or SMT package.
- 2) High transition frequency. ($f_T=1.5\text{GHz}$)
- 3) Low output capacitance. ($C_{ob}=0.9\text{pF}$)

●Equivalent circuits



●Absolute maximum ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	20	V
Emitter-base voltage	V_{EBO}	3	V
Collector current	I_C	50	mA
Collector power dissipation	EMX4 / UMX4N	P_C 150(TOTAL)	mW *1
	IMX4	300(TOTAL)	
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

*1 120mW per element must not be exceeded.
*2 200mW per element must not be exceeded.

●Package, marking, and packaging specifications

Type	EMX4	UMX4N	IMX4
Package	EMT6	UMT6	SMT6
Marking	X4	X4	X4
Code	T2R	TR	T108
Basic ordering unit (pieces)	8000	3000	3000

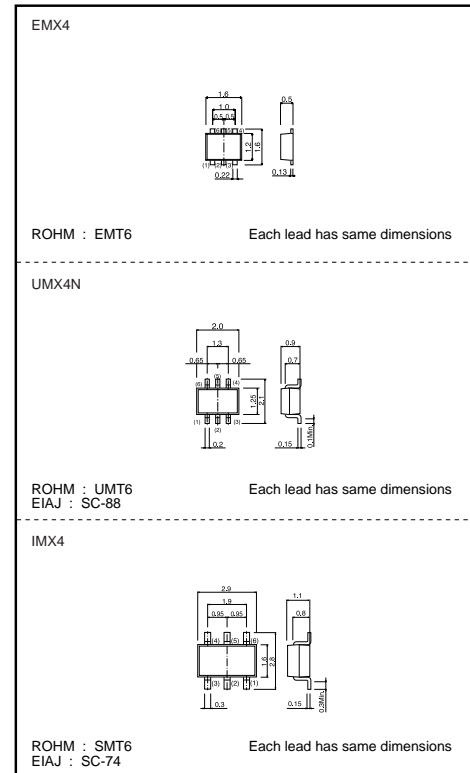
●Electrical characteristics ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	30	-	-	V	$I_C=10\mu\text{A}$
Collector-emitter breakdown voltage	BV_{CEO}	20	-	-	V	$I_C=1\text{mA}$
Emitter-base breakdown voltage	BV_{EBO}	3	-	-	V	$I_E=10\mu\text{A}$
Collector cutoff current	I_{CBO}	-	-	0.5	μA	$V_{CB}=15\text{V}$
Emitter cutoff current	I_{EBO}	-	-	0.5	μA	$V_{EB}=2\text{V}$
DC current transfer ratio	h_{FE}	56	-	180	-	$V_{CE}/I_C=10\text{V}/10\text{mA}$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-	0.5	V	$I_C/I_E=20\text{mA}/4\text{mA}$
Transition frequency	f_T	600	1500	-	MHz	$V_{CE}/I_E=10\text{V}/-10\text{mA}$, $f=200\text{MHz}$ *
Output capacitance	C_{ob}	-	0.95	1.6	pF	$V_{CB}/f=10\text{V}/1\text{MHz}$, $I_E=0\text{A}$
Collector-base time constant	$\tau_{bb} \cdot C_c$	-	6	13	ps	$V_{CB}=10\text{V}$, $I_C=10\text{mA}$, $f=31.8\text{MHz}$
Noise factor	NF	-	4.5	-	dB	$V_{CE}=12\text{V}$, $I_C=2\text{mA}$, $f=200\text{MHz}$, $R_g=50\Omega$

*Transition frequency of the device.

This product might cause chip aging and breakdown under the large electrified environment.
Please consider to design ESD protection circuit.

●Dimensions (Unit : mm)



Transistors

●Electrical characteristic curves

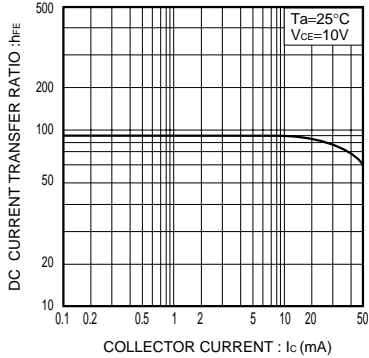


Fig.1 DC current gain vs. collector current

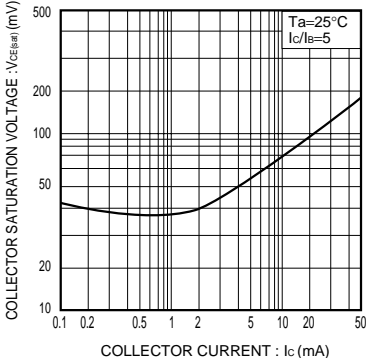


Fig.2 Collector-emitter saturation voltage vs. collector current

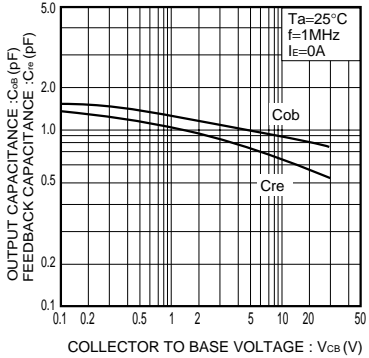


Fig.3 Capacitance vs. reverse bias voltage

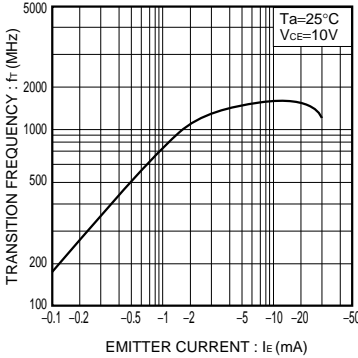


Fig.4 Gain bandwidth product vs. emitter current

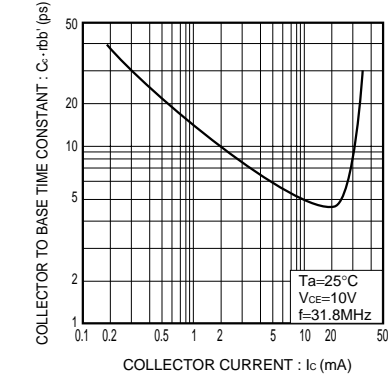


Fig.5 Collector to base time constant vs. collector current

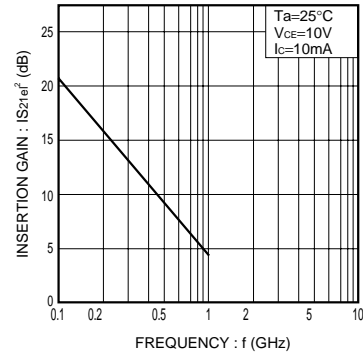


Fig.6 Insertion gain vs. frequency

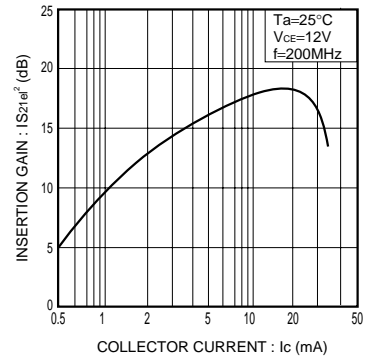


Fig.7 Insertion gain vs. collector current

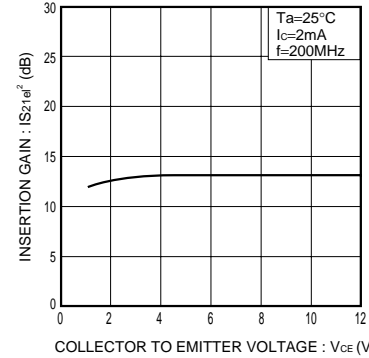


Fig.8 Insertion gain vs. collector voltage

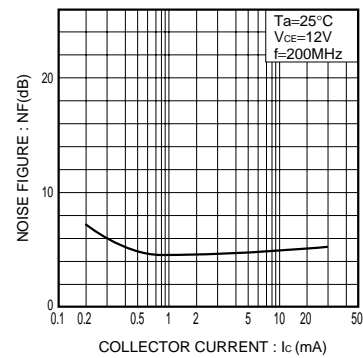


Fig.9 Noise factor vs. collector current

Transistors

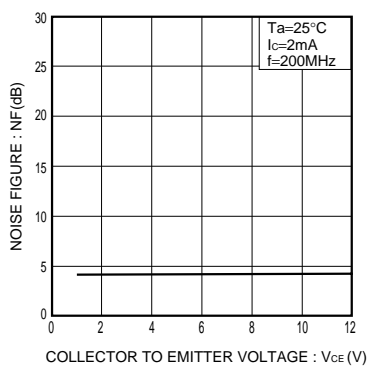


Fig.10 Noise factor vs. collector voltage

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

ROHM Customer Support System

THE AMERICAS / EUROPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@rohm.co.jp

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [ROHM manufacturer](#):

Other Similar products are found below :

[619691C](#) [MCH4017-TL-H](#) [BC546/116](#) [BC557/116](#) [BSW67A](#) [NTE158](#) [NTE187A](#) [NTE195A](#) [NTE2302](#) [NTE2330](#) [NTE63](#) [C4460](#)
[2SA1419T-TD-H](#) [2SA1721-O\(TE85L,F\)](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [2SC5488A-TL-H](#) [2SD2150T100R](#) [SP000011176](#) [FMMTA92QTA](#)
[2N2369ADCSM](#) [2SC2412KT146S](#) [2SC5490A-TL-H](#) [2SD1816S-TL-E](#) [2SD1816T-TL-E](#) [CMXT2207 TR](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#)
[US6T6TR](#) [732314D](#) [CMXT3906 TR](#) [CPH3121-TL-E](#) [CPH6021-TL-H](#) [873787E](#) [IMZ2AT108](#) [UMX21NTR](#) [EMT2T2R](#) [MCH6102-TL-E](#)
[FP204-TL-E](#) [NJL0302DG](#) [2N3583](#) [2SA1434-TB-E](#) [2SC3143-4-TB-E](#) [2SD1621S-TD-E](#) [NTE103](#) [30A02MH-TL-E](#) [NSV40301MZ4T1G](#)
[NTE101](#) [NTE13](#) [NTE15](#)